NPN Triple Diffused Planar Silicon Transistor



2SC3992

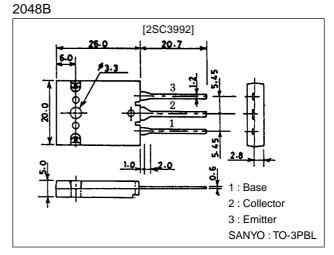
800V/12A Switching Regulator Applications

Features

- \cdot High breakdown voltage, high reliability.
- · Fast switching speed.
- \cdot Wide ASO.
- · Adoption of MBIT process.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		1100	V
Collector-to-Emitter Voltage	VCEO		800	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	IC		12	A
Collector Current (Pulse)	I _{CP}	PW≤300µs, duty cycle≤10%	30	A
Base Current	Ι _Β		6	A
Collector Dissipation	PC	Tc=25°C	200	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

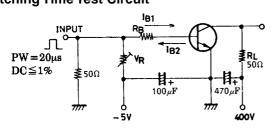
Parameter	Symbol	Conditions	Unit
i alameter		min typ max	
Collector Cutoff Current	ICBO	V _{CB} =800V, I _E =0 10	μA
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0 10	μΑ
DC Current Gain	h _{FE} 1	V _{CE} =5V, I _C =0.8A 10* 40*	
	h _{FE} 2	V _{CE} =5V, I _C =4A 8	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =0.8A 15	MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz 215	pF
* : The 2SC3992 is classified by 0.8A h _{FE} as foll	ows : 10	K 20 15 L 30 20 M 40	

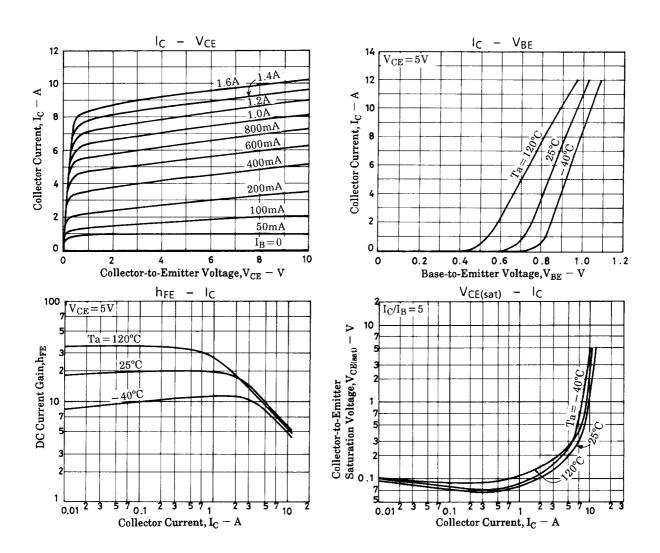
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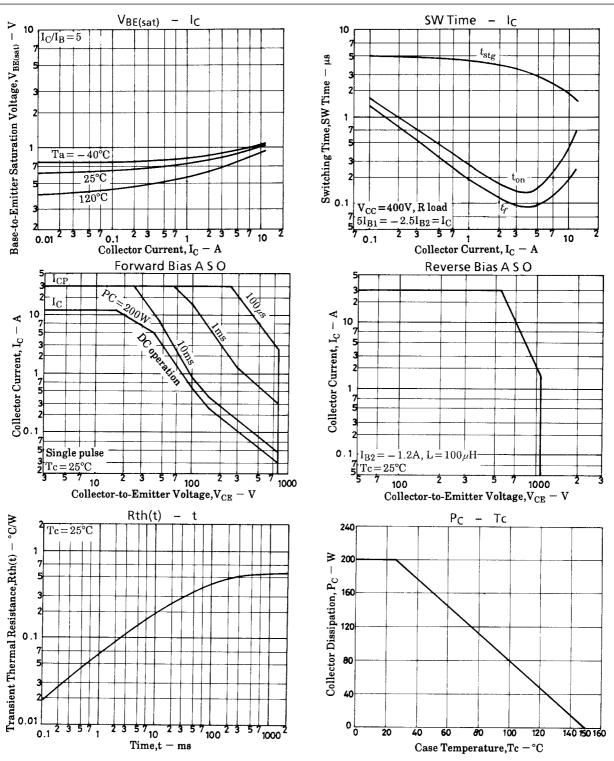
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =6A, I _B =1.2A			2.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =6A, I _B =1.2A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =1mA, I _E =0	1100			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =5mA, R _{BE} =∞	800			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=1mA, IC=0	7			V
Collector-to-Emitter Sustain Voltage	V _{CEX(sus)}	I _C =6A, I _{B1} =-I _{B2} =-1.2A, L=500µH, clamped	800			V
Turn-ON Time	ton	V_{CC} =400V, 5I _{B1} =-2.5I _{B2} =I _C =8A, R _L =50 Ω			0.5	μs
Storage Time	tstg	$V_{CC}=400V, 5I_{B1}=-2.5I_{B2}=I_{C}=8A, R_{L}=50\Omega$			3.0	μs
Fall Time	t _f	V_{CC} =400V, 5I _{B1} =-2.5I _{B2} =I _C =8A, R _L =50 Ω			0.3	μs

Switching Time Test Circuit







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